

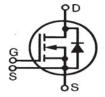
Symbol

# Linear L2<sup>™</sup> Power MOSFET w/ Extended FBSOA

## **IXTN90N25L2**

N-Channel Enhancement Mode Guaranteed FBSOA Avalanche Rated

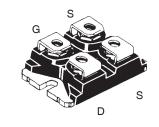
**Test Conditions** 



**Maximum Ratings** 

$\mathbf{V}_{\mathtt{DSS}}$	=	250V
I <sub>D25</sub>	=	90A
R <sub>DS(on)</sub>	≤	36mΩ





G = Gate	D = Drain
S = Source	

Either Source Terminal S can be used as the Source Terminal or the Kelvin Source (Gate Return) Terminal.

-,				
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 150°	°C	250	V
$\mathbf{V}_{\mathtt{DGR}}$	$T_{J} = 25^{\circ} \text{C to } 150^{\circ}$	$^{\circ}$ C, R <sub>GS</sub> = 1M $\Omega$	250	V
V <sub>GSS</sub>	Continuous		±20	V
$V_{GSM}$	Transient		±30	V
I <sub>D25</sub>	T <sub>c</sub> =25°C		90	A
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse	Width Limited by $T_{_{\rm JM}}$	360	Α
I <sub>A</sub>	T <sub>c</sub> =25°C		45	A
E <sub>AS</sub>	$T_{c} = 25^{\circ}C$		3	J
$P_{D}$	T <sub>C</sub> =25°C		735	W
T <sub>J</sub>			-55 +150	°C
Τ			150	°C
T <sub>stg</sub>			-55 +150	°C
V <sub>ISOL</sub>	50/60 Hz, RMS	t = 1 minute	2500	V~
	$I_{ISOL} \leq 1 mA$	t = 1 second	3000	V~
M <sub>d</sub>	Mounting Torque		1.5/13	Nm/lb.in
	Terminal Connect	tion Torque	1.3/11.5	Nm/lb.in
Weight			30	a

#### **Features**

- Designed for Linear Operation
- International Standard Package
- Guaranteed FBSOA at 75°C
- Avalanche Rated
- Molding Epoxy Meets UL94 V-0 Flammability Classification
- MiniBLOC with Aluminium Nitride Isolation

#### **Applications**

- Programmable Loads
- Current Regulators
- DC-DC Converters
- Battery Chargers
- DC Choppers
- Temperature and Lighting Controls

#### **Advantages**

- Easy to Mount
- Space Savings
- High Power Density

SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		teristic Values  Typ.   Max.		
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 1mA$	250		V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 3mA$	2.0		4.5 V
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$			±200 nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			50 μA 2.5 mA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 45A, \text{ Note 1}$			36 mΩ





Symbol (T <sub>J</sub> = 25°C, U	Test Conditions Unless Otherwise Specified)	Characteristic Values Min.   Typ.   Max.			
g <sub>fs</sub>	$V_{DS} = 10V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$	35	50	65	S
C <sub>iss</sub>			23		nF
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		2140		рF
C <sub>rss</sub>			360		рF
t <sub>d(on)</sub>			50		ns
t,	Resistive Switching Times		175		ns
t <sub>d(off)</sub>	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 0.5 \cdot I_{D25}$ $R_{G} = 1\Omega$ (External)		40		ns
t <sub>f</sub>	II <sub>G</sub> = 152 (External)		160		ns
$Q_{g(on)}$			640	ı	nC
Q <sub>gs</sub>	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$		125	1	nC
$\mathbf{Q}_{\mathrm{gd}}$			385		nC
R <sub>thJC</sub>				0.17 °C/	W
R <sub>thCS</sub>			0.05	°C/	W

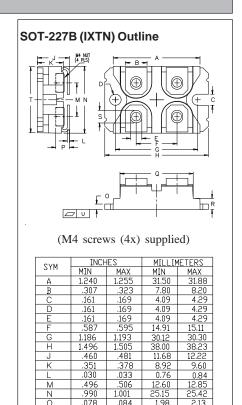
### **Safe Operating Area Specification**

Symbol	Test Conditions	Min.	Тур.	Max.
SOA	$V_{DS} = 250V, I_{D} = 1.4A, T_{C} = 75^{\circ}C, tp = 3s$	350		W

#### Source-Drain Diode

SymbolTest ConditionsCha $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		acteristic Values Typ.   Max.		
<b>I</b> s	$V_{GS} = 0V$		90	Α
SM	Repetitive, Pulse Width Limited by $T_{_{\rm JM}}$		360	Α
$V_{_{\mathrm{SD}}}$	$I_F = 45A, V_{GS} = 0V, \text{ Note 1}$		1.5	V
t <sub>rr</sub>	$I_{\rm F} = 45 \text{A}, -\text{di/dt} = 100 \text{A}/\mu \text{s}$	266 23		ns A
$Q_{_{\mathrm{RM}}}$	$V_R = 80V, V_{GS} = 0V$	3.0		μC

1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ . Note:



.084

.004

-.002

26.90 4.42 4.85 25.07

0.1

-0.05

7,005,734 B2 7,157,338B2

7,063,975 B2



Fig. 1. Output Characteristics @ T<sub>J</sub> = 25°C

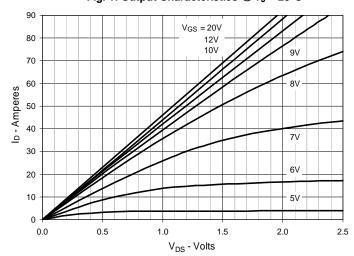


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

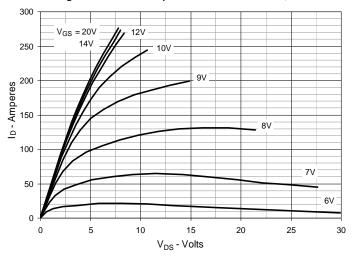


Fig. 3. Output Characteristics @ T<sub>J</sub> = 125°C

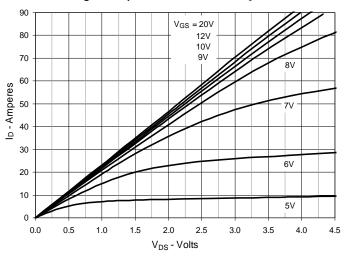


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 45A Value vs. Junction Temperature

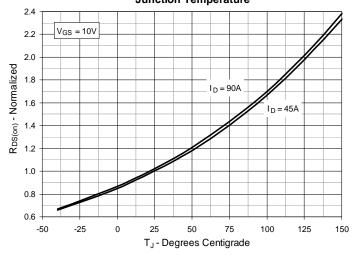


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D$  = 45A Value vs.

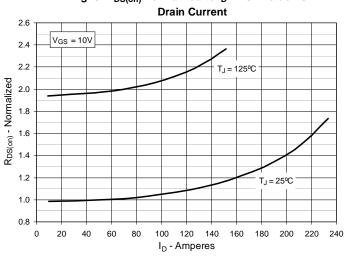
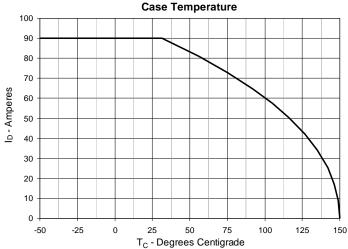
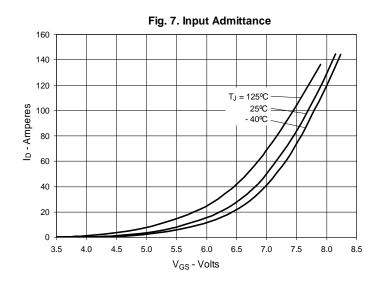
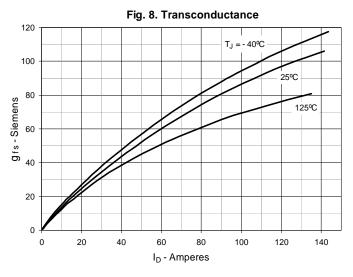


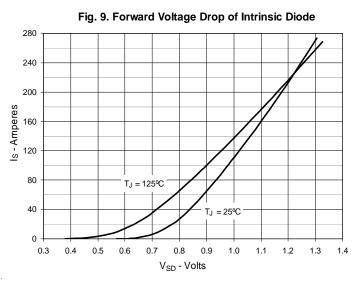
Fig. 6. Maximum Drain Current vs.

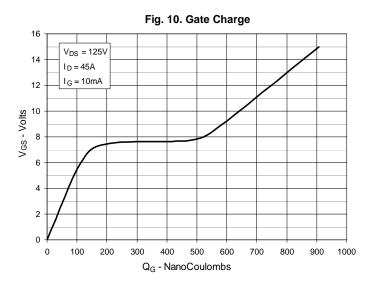


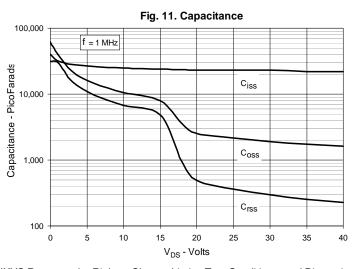


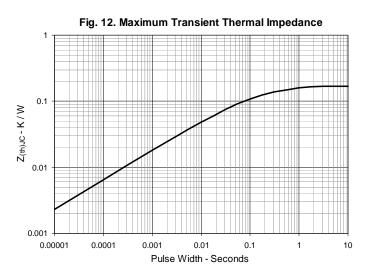












 $\ensuremath{\mathsf{IXYS}}$  Reserves the Right to Change Limits, Test Conditions, and Dimensions.



Fig. 13. Forward-Bias Safe Operating Area

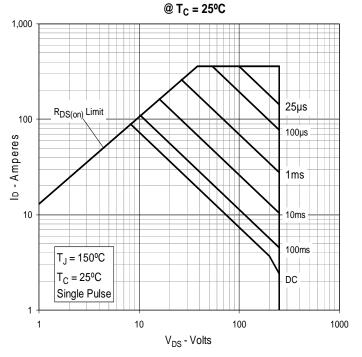


Fig. 14. Forward-Bias Safe Operating Area

